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# 2SJ451

Silicon P-Channel MOS FET

# HITACHI

ADE-208-382  
1st. Edition

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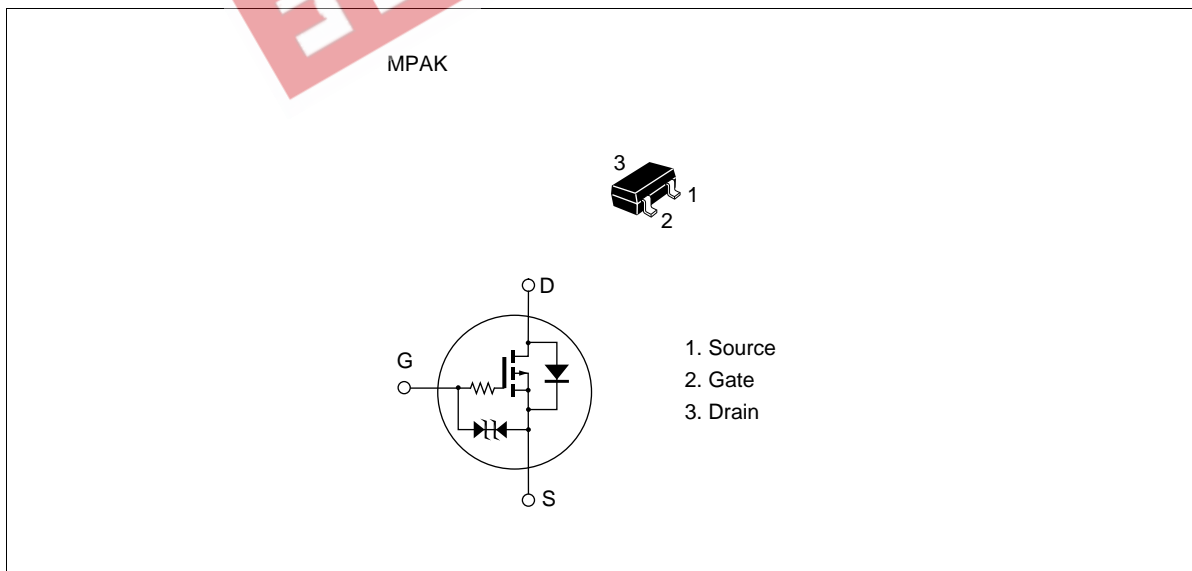
## Application

Low frequency power switching

## Features

- Low on-resistance.
- Low drive power
- 2.5 V gate drive device.
- Small package (MPAK).

## Outline



## 2SJ451

### Absolute Maximum Ratings (Ta = 25°C)

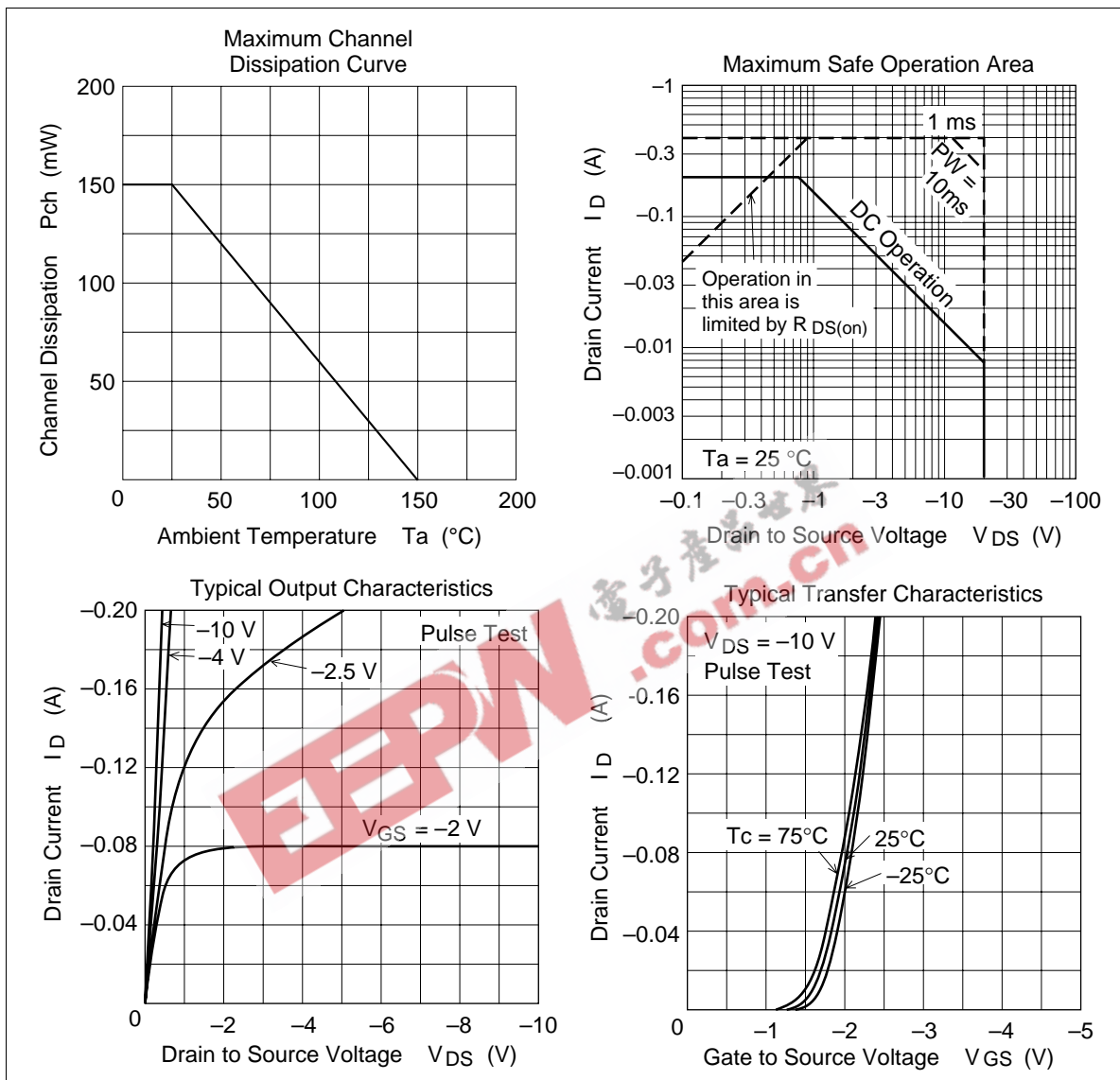
Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	-20	V
Gate to source voltage	$V_{GSS}$	±20	V
Drain current	$I_D$	-0.2	A
Drain peak current	$I_{D(pulse)}^{*1}$	-0.4	A
Channel dissipation	Pch	150	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

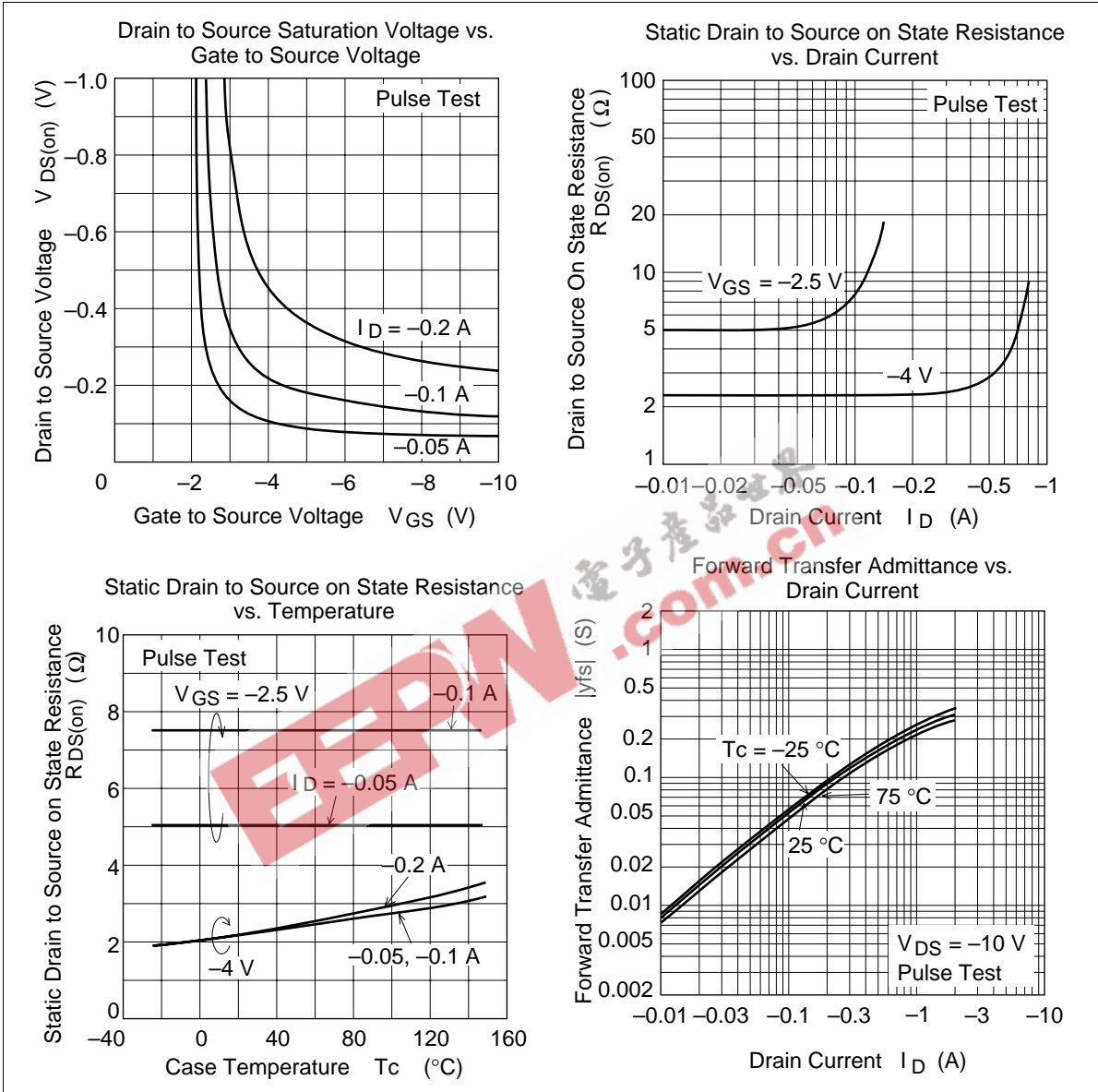
Note: 1.  $PW \leq 10 \mu s$ , duty cycle  $\leq 1\%$   
Marking is "ZK-".

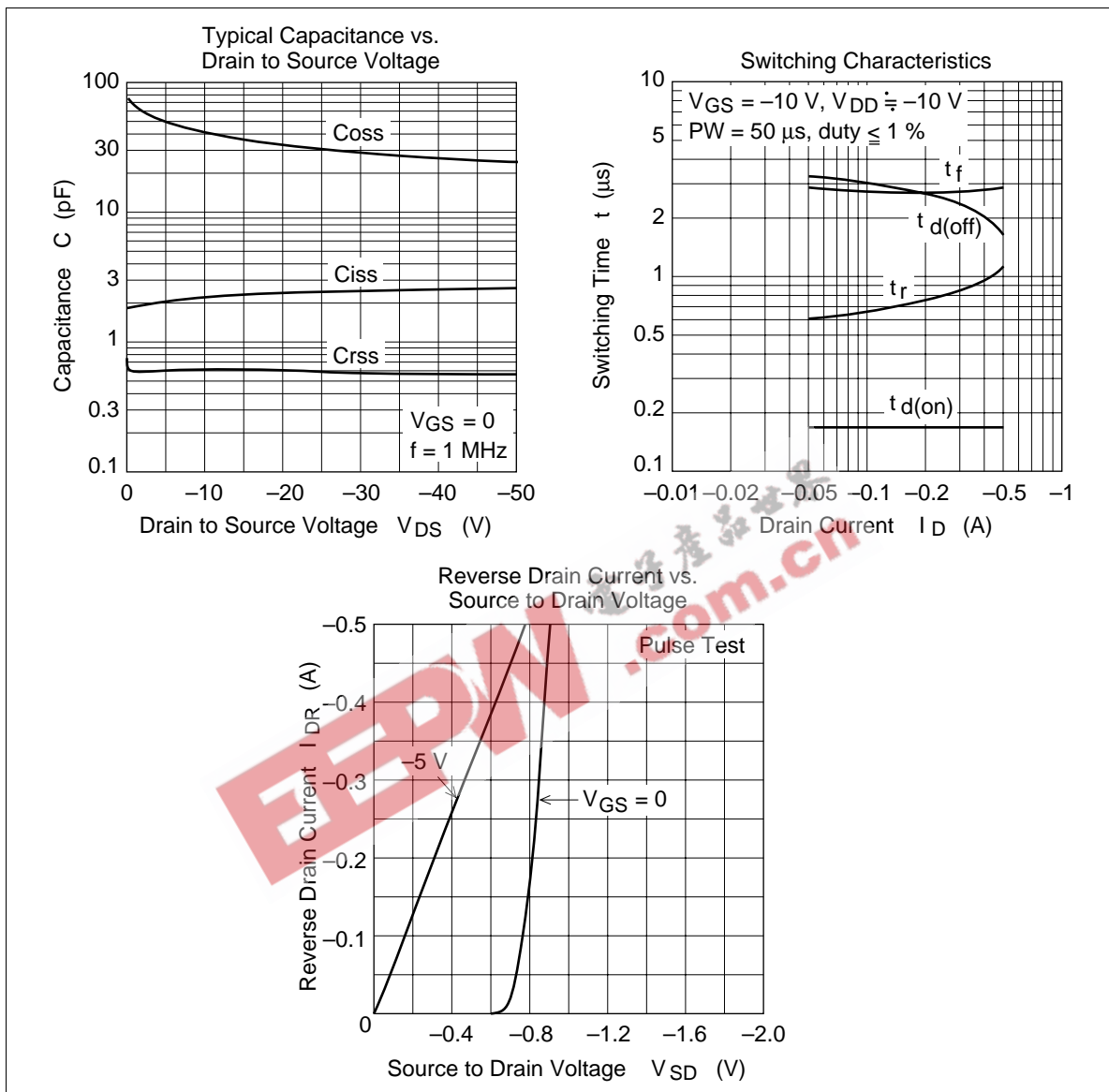
### Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-20	—	—	V	$I_D = -100 \mu A$ , $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	—	—	V	$I_G = \pm 100 \mu A$ , $V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	-1.0	$\mu A$	$V_{DS} = -16 V$ , $V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	±2.0	$\mu A$	$V_{GS} = \pm 16 V$ , $V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-0.5	—	-1.5	V	$I_D = -10 \mu A$ , $V_{DS} = -5 V$
Static drain to source on state resistance	$R_{DS(on)1}$	—	2.3	3.5	$\Omega$	$I_D = -100 mA$ $V_{GS} = -4 V^{*1}$
Static drain to source on state resistance	$R_{DS(on)2}$	—	5.0	9.0	$\Omega$	$I_D = -40 mA$ $V_{GS} = -2.5 V^{*1}$
Forward transfer admittance	$ y_{fs} $	0.13	0.23	—	S	$I_D = -100 mA^{*1}$ $V_{DS} = -10 V$
Input capacitance	$C_{iss}$	—	2.4	—	pF	$V_{DS} = -10 V$
Output capacitance	$C_{oss}$	—	31	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	$C_{rss}$	—	0.6	—	pF	$f = 1 MHz$
Turn-on delay time	$t_{d(on)}$	—	0.17	—	$\mu s$	$V_{GS} = -10 V$ , $I_D = -0.1 A$
Rise time	$t_r$	—	0.68	—	$\mu s$	$R_L = 100 \Omega$
Turn-off delay time	$t_{d(off)}$	—	3.0	—	$\mu s$	
Fall time	$t_f$	—	2.8	—	$\mu s$	

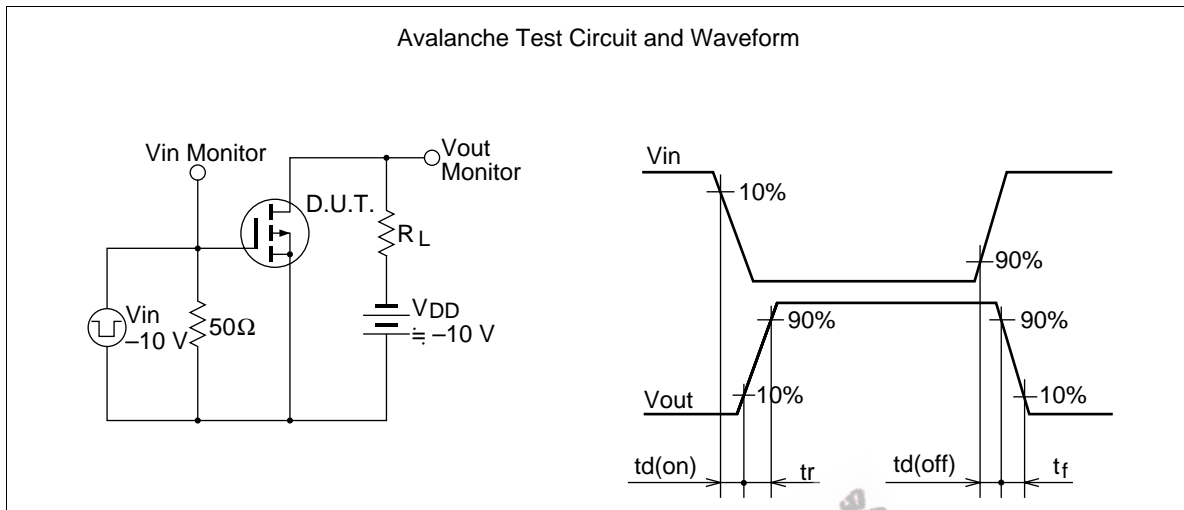
Note: 1. Pulse Test





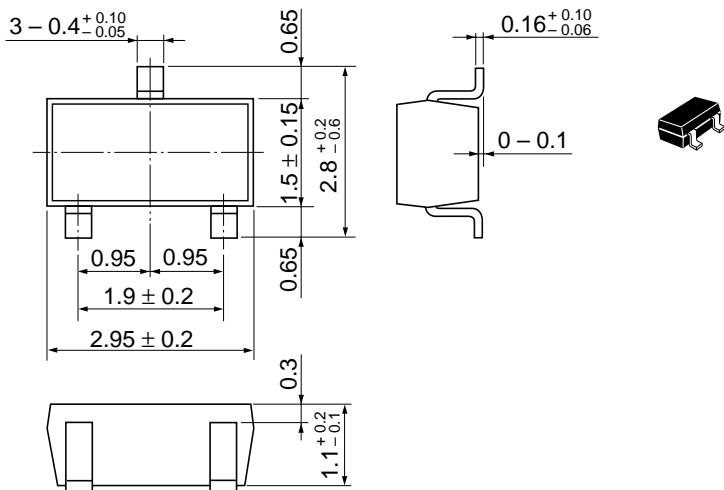


## 2SJ451



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Unit: mm



Hitachi Code	MPAK
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.011 g

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